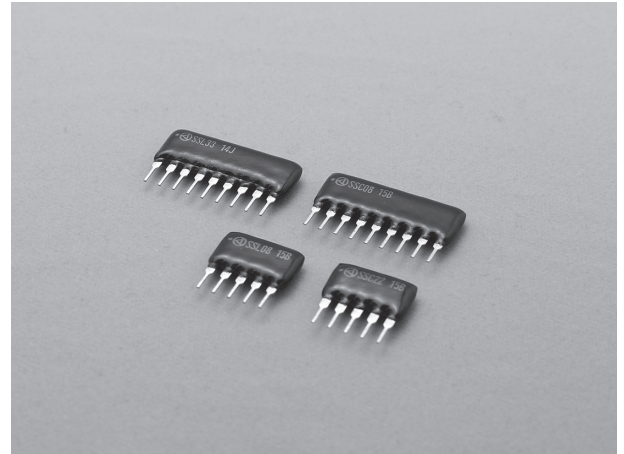
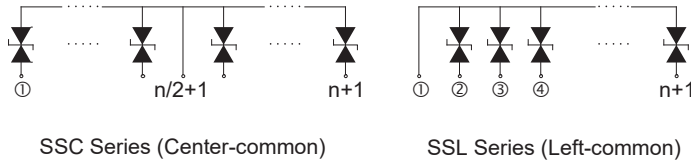




This array type of silicon surge absorber is designed for use in signal line applications. The element's integration is enhanced, so space factor and process times are much improved. You can choose 4 or 8 elements, and center-common or left-common.

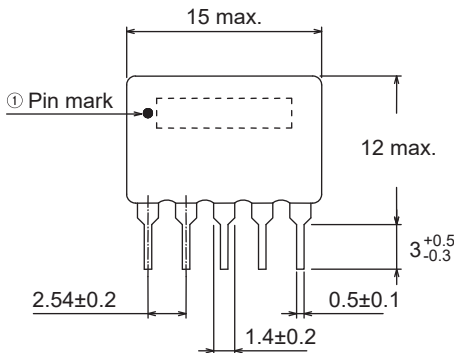


● **Circuit**

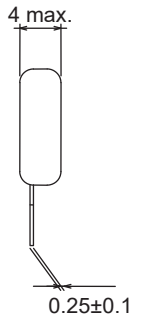
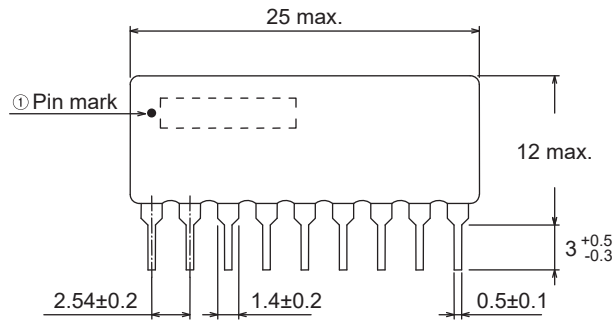


● **Dimensions**

4 elements



8 elements



Unit: mm

Electrical Specifications

Rated Peak Impulse Power Dissipation 4,200W (8/20μsec)

Model Number*	Nominal Breakdown Voltage		Maximum Working Voltage		Rated Peak Impulse Current 8/20μsec		
	V _{BR} (V)	I _T (mA)	V _{WM} (V)	I _R (μA)	I _{PPM} (A)	V _C (V)	
SS□08-O	8.2	1	6.63	300	180.0	23.3	
SS□18-O	18.0		14.5		5	128.0	32.7
SS□22-O	22.0		17.8			105.0	40.0
SS□33-O	33.0		26.8			70.1	59.9

*□: Circuit symbol: C= Center-common, L= left-common O: Number of element: 4 or 8
Operating Temperature: -40~+125°C